

FEATURES

- Fixed gain of 15 dB
- Operation from 50 MHz to 4.0 GHz
- Highest dynamic range gain block
- Input/output internally matched to 50 Ω
- Integrated bias control circuit
- OIP3 of 43.0 dBm at 900 MHz
- P1dB of 19.0 dBm at 900 MHz
- Noise figure of 3.7 dB at 900 MHz
- Single 5 V power supply
- Low quiescent current of 83 mA
- Thermally efficient SOT-89 package
- ESD rating of ± 1.5 kV (Class 1C)

GENERAL DESCRIPTION

The [ADL5601](#) is a broadband, 15 dB linear amplifier that operates at frequencies up to 4.0 GHz. The device can be used in a wide variety of cellular, cable television (CATV), military, and instrumentation equipment.

The [ADL5601](#) provides the highest dynamic range available from an internally matched gain block. This is accomplished by providing extremely low noise figures and very high OIP3 specifications simultaneously, across the entire 4.0 GHz frequency range.

The [ADL5601](#) provides a gain of 15 dB, which is stable over frequency, temperature, and supply voltage, as well as from device to device. The device is internally matched to 50 Ω at the input and output, making the [ADL5601](#) very easy to implement in a wide

FUNCTIONAL BLOCK DIAGRAM

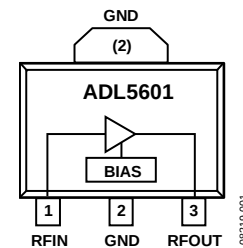


Figure 1.

variety of applications. Only input/output ac coupling capacitors, power supply decoupling capacitors, and an external inductor are required for operation.

The [ADL5601](#) is fabricated on an InGaP heterojunction bipolar transistor (HBT) process and has an ESD rating of ± 1.5 kV (Class 1C). The device is available in a thermally efficient SOT-89 package.

The [ADL5601](#) consumes 83 mA on a single 5 V supply and is fully specified for operation from -40°C to $+85^{\circ}\text{C}$.

A fully populated RoHS-compliant evaluation board is available.

ADL5601* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- ADL5601 Evaluation Board

DOCUMENTATION

Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers

Data Sheet

- ADL5601: 50 MHz to 4.0 GHz RF/IF Gain Block Data Sheet

TOOLS AND SIMULATIONS

- ADI RF Amplifier Library for Agilent ADS
- ADIsimPLL™
- ADIsimRF
- ADL5601 S Parameters

REFERENCE MATERIALS

Product Selection Guide

- RF Source Booklet

DESIGN RESOURCES

- ADL5601 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all ADL5601 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.

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REVISION HISTORY

11/13—Rev. 0 to Rev. A

Added Figure 15, Renumbered Sequentially	11
Changes to Figure 17	12
Updated Outline Dimensions	15

9/09—Revision 0: Initial Version

SPECIFICATIONS

$V_{CC} = 5\text{ V}$ and $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 1.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
OVERALL FUNCTION					
Frequency Range		50		4000	MHz
FREQUENCY = 50 MHz					
Gain			15.6		dB
Output 1 dB Compression Point (P1dB)			16.3		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1\text{ MHz}$, output power (P_{OUT}) = 0 dBm per tone		34.0		dBm
Second Harmonic	$P_{OUT} = 0\text{ dBm}$		-50.7		dBc
Third Harmonic	$P_{OUT} = 0\text{ dBm}$		-78.7		dBc
Noise Figure			3.9		dB
FREQUENCY = 140 MHz					
Gain			15.4		dB
vs. Frequency	$\pm 50\text{ MHz}$		± 0.05		dB
vs. Temperature	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		± 0.19		dB
vs. Supply Voltage	4.75 V to 5.25 V		± 0.02		dB
Output 1 dB Compression Point (P1dB)			18.8		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1\text{ MHz}$, output power (P_{OUT}) = 0 dBm per tone		34.7		dBm
Second Harmonic	$P_{OUT} = 0\text{ dBm}$		-51.1		dBc
Third Harmonic	$P_{OUT} = 0\text{ dBm}$		-77.3		dBc
Noise Figure			3.8		dB
FREQUENCY = 350 MHz					
Gain			15.2		dB
vs. Frequency	$\pm 50\text{ MHz}$		± 0.02		dB
vs. Temperature	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		± 0.20		dB
vs. Supply Voltage	4.75 V to 5.25 V		± 0.02		dB
Output 1 dB Compression Point (P1dB)			19.1		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1\text{ MHz}$, output power (P_{OUT}) = 0 dBm per tone		35.8		dBm
Second Harmonic	$P_{OUT} = 0\text{ dBm}$		-53.8		dBc
Third Harmonic	$P_{OUT} = 0\text{ dBm}$		-82.9		dBc
Noise Figure			3.8		dB
FREQUENCY = 700 MHz					
Gain		14.3	15.2	16.5	dB
vs. Frequency	$\pm 50\text{ MHz}$		± 0.01		dB
vs. Temperature	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		± 0.21		dB
vs. Supply Voltage	4.75 V to 5.25 V		± 0.02		dB
Output 1 dB Compression Point (P1dB)		18.0	19.0		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1\text{ MHz}$, output power (P_{OUT}) = 0 dBm per tone		40.7		dBm
Second Harmonic	$P_{OUT} = 0\text{ dBm}$		-55.6		dBc
Third Harmonic	$P_{OUT} = 0\text{ dBm}$		-77.9		dBc
Noise Figure			3.8		dB

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
FREQUENCY = 900 MHz					
Gain		14.3	15.3	16.5	dB
vs. Frequency	± 50 MHz		± 0.01		dB
vs. Temperature	$-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$		± 0.22		dB
vs. Supply Voltage	4.75 V to 5.25 V		± 0.02		dB
Output 1 dB Compression Point (P1dB)		18.0	19.0		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1$ MHz, output power (P_{OUT}) = 0 dBm per tone		43.0		dBm
Second Harmonic	$P_{\text{OUT}} = 0$ dBm		-57.6		dBc
Third Harmonic	$P_{\text{OUT}} = 0$ dBm		-78.7		dBc
Noise Figure			3.7		dB
FREQUENCY = 2000 MHz					
Gain			14.2		dB
vs. Frequency	± 50 MHz		± 0.08		dB
vs. Temperature	$-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$		± 0.27		dB
vs. Supply Voltage	4.75 V to 5.25 V		± 0.03		dB
Output 1 dB Compression Point (P1dB)			17.5		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1$ MHz, output power (P_{OUT}) = 0 dBm per tone		34.2		dBm
Second Harmonic	$P_{\text{OUT}} = 0$ dBm		-41.9		dBc
Third Harmonic	$P_{\text{OUT}} = 0$ dBm		-67.3		dBc
Noise Figure			4.5		dB
FREQUENCY = 2600 MHz					
Gain			13.4		dB
vs. Frequency	± 50 MHz		± 0.04		dB
vs. Temperature	$-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$		± 0.20		dB
vs. Supply Voltage	4.75 V to 5.25 V		± 0.04		dB
Output 1 dB Compression Point (P1dB)			16.0		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1$ MHz, output power (P_{OUT}) = 0 dBm per tone		30.7		dBm
Second Harmonic	$P_{\text{OUT}} = 0$ dBm		-46.4		dBc
Third Harmonic	$P_{\text{OUT}} = 0$ dBm		-65.4		dBc
Noise Figure			4.7		dB
FREQUENCY = 3500 MHz					
Gain			12.9		dB
vs. Frequency	± 50 MHz		± 0.06		dB
vs. Temperature	$-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$		± 0.32		dB
vs. Supply Voltage	4.75 V to 5.25 V		± 0.05		dB
Output 1 dB Compression Point (P1dB)			14.2		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1$ MHz, output power (P_{OUT}) = 0 dBm per tone		26.7		dBm
Second Harmonic	$P_{\text{OUT}} = 0$ dBm		-41.0		dBc
Third Harmonic	$P_{\text{OUT}} = 0$ dBm		-62.4		dBc
Noise Figure			5.5		dB
FREQUENCY = 4000 MHz					
Gain			12.1		dB
vs. Frequency	± 50 MHz		± 0.11		dB
vs. Temperature	$-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$		± 0.50		dB
vs. Supply Voltage	4.75 V to 5.25 V		± 0.05		dB
Output 1 dB Compression Point (P1dB)			12.7		dBm
Output Third-Order Intercept (OIP3)	$\Delta f = 1$ MHz, output power (P_{OUT}) = 0 dBm per tone		24.7		dBm
Second Harmonic	$P_{\text{OUT}} = 0$ dBm		-41.0		dBc
Third Harmonic	$P_{\text{OUT}} = 0$ dBm		-59.7		dBc
Noise Figure			6.1		dB

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
POWER INTERFACE	VCC	4.5	5.0	5.5	V
Supply Voltage (V _{CC})			83	100	mA
Supply Current vs. Temperature	−40°C ≤ T _A ≤ +85°C		±2.3		mA
Power Dissipation	V _{CC} = 5 V		0.42		W

TYPICAL SCATTERING PARAMETERS (S-PARAMETERS)

V_{CC} = 5 V, T_A = 25°C, and the effects of the evaluation board have been deembedded up to the pins of the device.

Table 2.

Frequency (MHz)	S11		S21		S12		S22	
	Magnitude (dB)	Angle (°)	Magnitude (dB)	Angle (°)	Magnitude (dB)	Angle (°)	Magnitude (dB)	Angle (°)
50	−20.65	−144.57	+15.59	+161.69	−19.76	−7.97	−16.61	−168.75
100	−25.05	+175.09	+15.34	+149.77	−19.85	−24.47	−16.06	+164.97
150	−25.57	+149.73	+15.27	+136.48	−19.89	−38.84	−15.85	+145.84
200	−24.93	+130.36	+15.20	+122.75	−19.92	−52.66	−15.63	+128.22
250	−24.24	+114.36	+15.14	+108.91	−19.96	−66.22	−15.49	+112.53
300	−23.29	+101.24	+15.07	+95.06	−19.99	−79.64	−15.40	+98.52
350	−22.53	+88.38	+15.02	+81.26	−20.03	−92.91	−15.35	+84.79
400	−22.07	+76.45	+14.97	+67.39	−20.05	−106.12	−15.38	+71.26
450	−21.78	+66.13	+14.94	+53.57	−20.07	−119.35	−15.48	+58.84
500	−21.51	+55.91	+14.92	+39.81	−20.08	−132.53	−15.68	+46.57
550	−21.57	+46.37	+14.90	+25.97	−20.09	−145.77	−16.07	+34.25
600	−21.78	+38.11	+14.89	+12.17	−20.10	−159.04	−16.65	+22.42
650	−22.13	+30.61	+14.89	−1.54	−20.10	−172.37	−17.41	+10.91
700	−22.68	+23.62	+14.88	−15.54	−20.11	+174.38	−18.36	−0.29
750	−23.43	+18.47	+14.89	−29.41	−20.11	+161.06	−19.65	−10.39
800	−24.35	+16.37	+14.89	−43.49	−20.11	+147.71	−21.34	−18.60
850	−25.29	+16.28	+14.89	−57.51	−20.12	+134.31	−23.41	−25.16
900	−25.88	+20.10	+14.88	−71.67	−20.13	+120.86	−25.86	−26.32
950	−25.90	+25.78	+14.87	−85.39	−20.14	+107.34	−28.12	−18.10
1000	−25.31	+29.70	+14.87	−99.48	−20.16	+93.84	−28.73	−1.68
1050	−24.16	+29.42	+14.86	−113.64	−20.18	+80.32	−27.11	+8.91
1100	−23.38	+25.45	+14.83	−127.83	−20.22	+66.77	−25.16	+5.98
1150	−22.70	+20.88	+14.81	−141.81	−20.25	+53.39	−23.33	+1.75
1200	−22.10	+13.43	+14.80	−155.93	−20.27	+39.79	−22.27	−8.80
1250	−21.81	+4.90	+14.78	−170.15	−20.31	+26.19	−21.38	−21.30
1300	−21.78	−4.74	+14.75	+175.70	−20.35	+12.56	−20.75	−35.07
1350	−21.96	−15.31	+14.72	+161.57	−20.40	−1.10	−20.35	−50.07
1400	−22.31	−27.46	+14.68	+147.40	−20.44	−14.74	−20.06	−66.34
1450	−22.92	−40.13	+14.64	+133.17	−20.50	−28.45	−19.80	−83.25
1500	−23.53	−55.61	+14.60	+118.79	−20.56	−42.17	−19.60	−100.18
1550	−24.04	−74.40	+14.56	+104.52	−20.62	−55.96	−19.29	−117.80
1600	−24.50	−95.46	+14.49	+90.23	−20.70	−69.82	−18.83	−135.14
1650	−24.13	−118.14	+14.43	+75.97	−20.79	−83.66	−18.22	−150.53
1700	−23.01	−140.97	+14.37	+61.50	−20.89	−97.51	−17.57	−164.65
1750	−21.46	−161.36	+14.27	+47.04	−21.00	−111.39	−16.78	−177.64
1800	−19.67	−178.55	+14.18	+32.52	−21.12	−125.37	−15.91	+170.73
1850	−17.73	+167.17	+14.07	+18.07	−21.26	−139.35	−14.91	+160.24
1900	−15.95	+154.24	+13.92	+3.63	−21.42	−153.36	−13.88	+150.20
1950	−14.26	+141.96	+13.77	−10.89	−21.60	−167.35	−12.82	+140.45
2000	−12.72	+130.33	+13.60	−25.40	−21.81	+178.67	−11.79	+130.63
2050	−11.36	+119.00	+13.39	−39.85	−22.05	+164.79	−10.77	+120.32

Frequency (MHz)	S11		S21		S12		S22	
	Magnitude (dB)	Angle (°)	Magnitude (dB)	Angle (°)	Magnitude (dB)	Angle (°)	Magnitude (dB)	Angle (°)
2100	-10.11	+107.84	+13.16	-54.15	-22.31	+150.95	-9.78	+109.99
2150	-9.04	+96.61	+12.90	-68.23	-22.60	+137.28	-8.88	+99.58
2200	-8.12	+85.63	+12.63	-82.16	-22.91	+123.82	-8.12	+88.80
2250	-7.33	+74.68	+12.34	-95.90	-23.24	+110.57	-7.45	+77.69
2300	-6.66	+63.86	+12.04	-109.35	-23.59	+97.61	-6.85	+66.77
2350	-6.11	+53.33	+11.75	-122.46	-23.92	+84.90	-6.37	+55.88
2400	-5.65	+42.82	+11.46	-135.36	-24.25	+72.46	-6.00	+44.86
2450	-5.28	+32.51	+11.18	-147.97	-24.57	+60.24	-5.68	+33.86
2500	-5.00	+22.51	+10.94	-160.34	-24.86	+48.34	-5.44	+23.12
2550	-4.78	+12.49	+10.73	-172.61	-25.12	+36.64	-5.29	+12.46
2600	-4.64	+2.62	+10.56	+175.37	-25.33	+25.08	-5.19	+1.65
2650	-4.54	-7.06	+10.43	+163.51	-25.52	+13.55	-5.13	-9.06
2700	-4.50	-16.80	+10.35	+151.65	-25.66	+2.20	-5.13	-19.67
2750	-4.52	-26.55	+10.31	+139.80	-25.74	-9.14	-5.19	-30.41
2800	-4.60	-36.24	+10.32	+127.87	-25.78	-20.59	-5.27	-41.23
2850	-4.72	-46.09	+10.37	+115.83	-25.79	-32.13	-5.40	-52.01
2900	-4.92	-56.14	+10.47	+103.58	-25.75	-43.77	-5.60	-62.93
2950	-5.18	-66.18	+10.60	+91.16	-25.67	-55.71	-5.86	-74.10
3000	-5.52	-76.58	+10.76	+78.44	-25.57	-67.81	-6.16	-85.27
3050	-5.95	-87.31	+10.96	+65.65	-25.45	-80.30	-6.57	-96.63
3100	-6.50	-98.20	+11.16	+52.38	-25.30	-93.05	-7.07	-108.36
3150	-7.17	-109.56	+11.37	+38.77	-25.16	-106.14	-7.65	-120.33
3200	-7.96	-121.53	+11.59	+24.80	-25.03	-119.49	-8.35	-132.41
3250	-8.95	-134.08	+11.77	+10.48	-24.91	-133.23	-9.19	-144.97
3300	-10.11	-147.58	+11.94	-4.10	-24.71	-148.47	-10.19	-157.59
3350	-11.43	-162.30	+12.09	-18.93	-24.64	-162.78	-11.23	-171.07
3400	-12.93	-178.72	+12.18	-34.00	-24.61	-177.32	-12.44	+174.45
3450	-14.51	+161.78	+12.24	-49.17	-24.63	+168.07	-13.64	+158.38
3500	-15.96	+138.82	+12.26	-64.42	-24.69	+153.27	-14.74	+140.90
3550	-16.86	+111.84	+12.24	-79.75	-24.80	+138.48	-15.67	+121.24
3600	-16.83	+83.89	+12.17	-95.04	-24.97	+123.67	-16.20	+98.98
3650	-15.98	+58.24	+12.06	-110.33	-25.15	+108.97	-15.98	+76.14
3700	-14.75	+36.92	+11.92	-125.55	-25.39	+94.34	-15.33	+55.10
3750	-13.43	+18.94	+11.76	-140.74	-25.66	+79.90	-14.38	+35.05
3800	-12.23	+3.37	+11.54	-155.80	-25.97	+65.42	-13.18	+17.14
3850	-11.21	-10.83	+11.31	-170.64	-26.33	+51.35	-12.03	+1.60
3900	-10.32	-24.29	+11.05	+174.74	-26.71	+37.49	-11.04	-12.99
3950	-9.59	-37.18	+10.78	+160.27	-27.07	+23.89	-10.13	-27.31
4000	-8.99	-49.64	+10.49	+146.04	-27.43	+10.62	-9.28	-40.73

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Supply Voltage, V_{CC}	6.5 V
Input Power (Referred to 50 Ω)	16 dBm
Internal Power Dissipation (Paddle Soldered)	600 mW
θ_{JA} (Junction to Air)	30.7°C/W
θ_{JC} (Junction to Paddle)	5.0°C/W
Maximum Junction Temperature	150°C
Lead Temperature (Soldering, 60 sec)	240°C
Operating Temperature Range	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

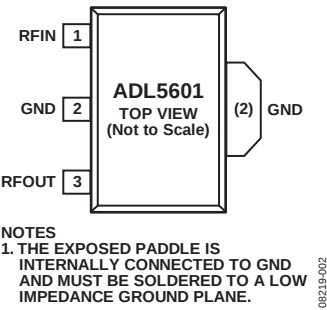


Figure 2. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	RFIN	RF Input. This pin requires a dc blocking capacitor.
2	GND	Ground. Connect this pin to a low impedance ground plane.
3	RFOUT	RF Output and Supply Voltage. A dc bias is provided to this pin through an inductor that is connected to the external power supply. The RF path requires a dc blocking capacitor.
(2)	Exposed Paddle	Exposed Paddle. The exposed paddle is internally connected to GND and must be soldered to a low impedance ground plane.

TYPICAL PERFORMANCE CHARACTERISTICS

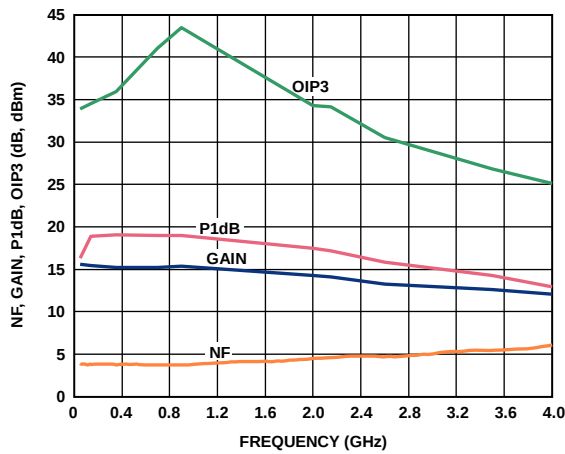


Figure 3. Noise Figure, Gain, P1dB, and OIP3 vs. Frequency

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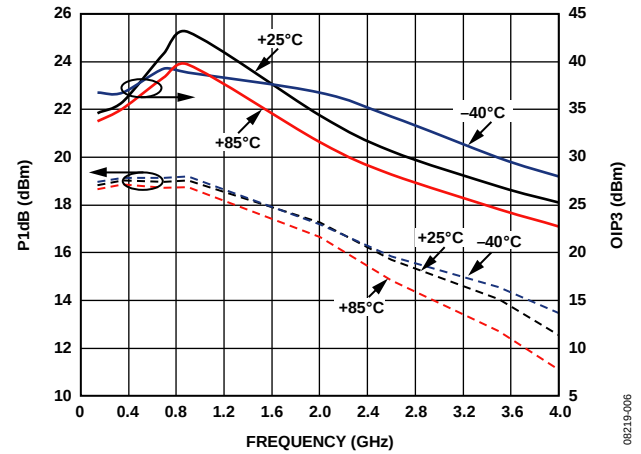


Figure 6. P1dB and OIP3 vs. Frequency and Temperature

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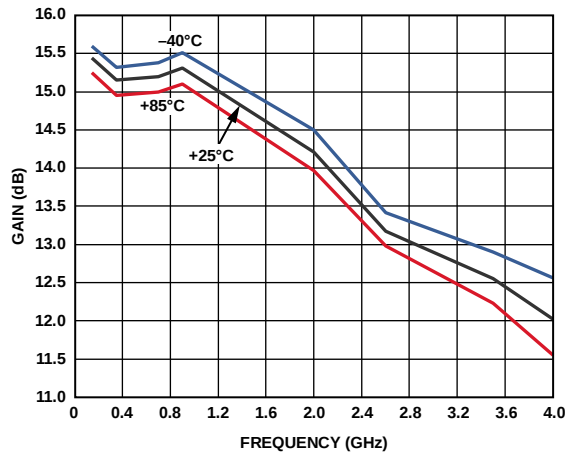
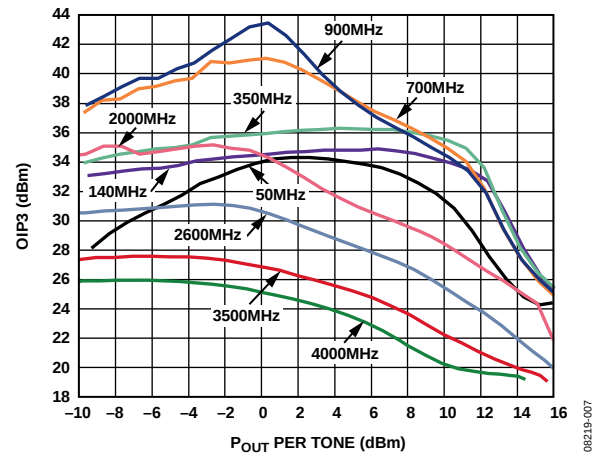


Figure 4. Gain vs. Frequency and Temperature

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Figure 7. OIP3 vs. Output Power (P_{OUT}) and Frequency

08219-007

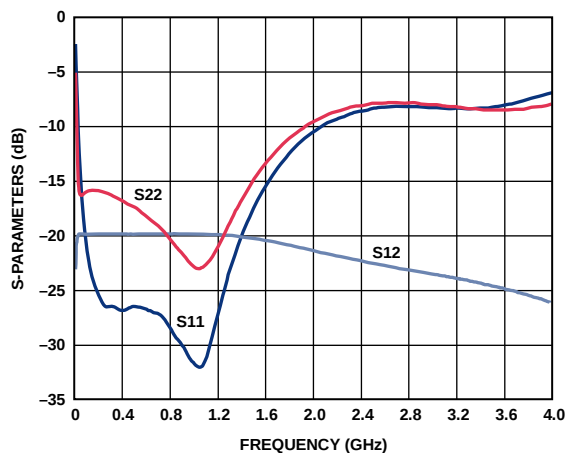


Figure 5. Input Return Loss (S11), Output Return Loss (S22), and Reverse Isolation (S12) vs. Frequency

08219-021

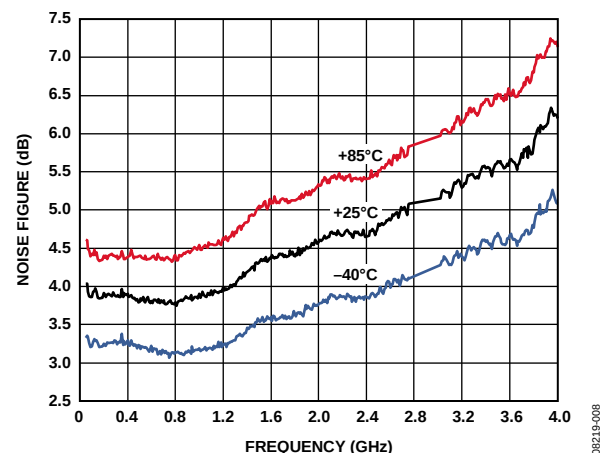


Figure 8. Noise Figure vs. Frequency and Temperature

08219-008

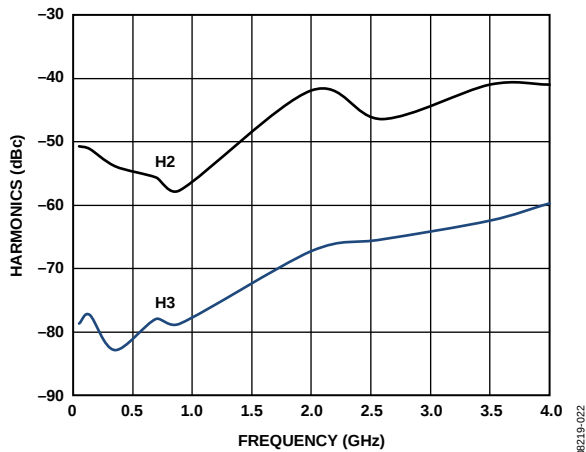
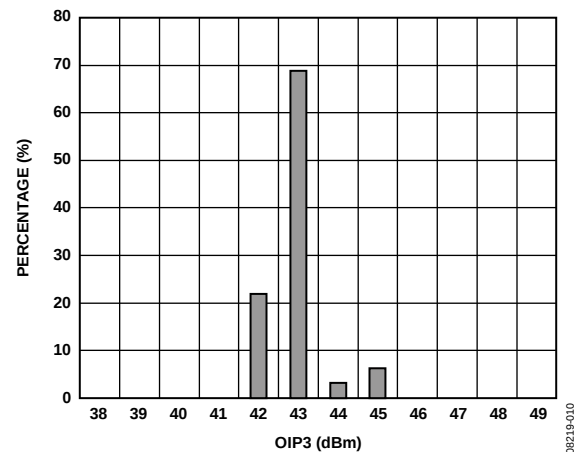
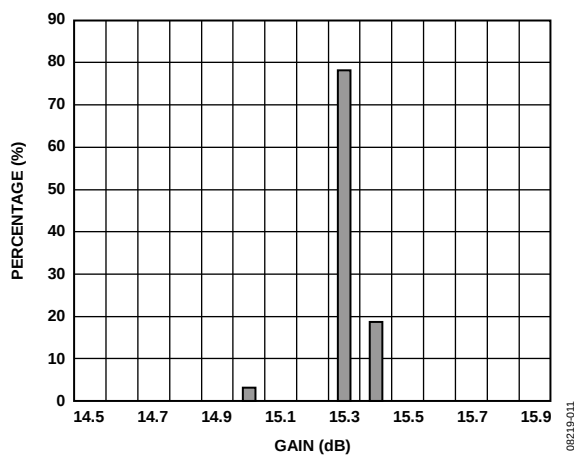
Figure 9. Single-Tone Harmonics vs. Frequency, $P_{OUT} = 0$ dBmFigure 12. OIP3 Distribution at 900 MHz, $P_{OUT} = 0$ dBm

Figure 10. Gain Distribution at 900 MHz

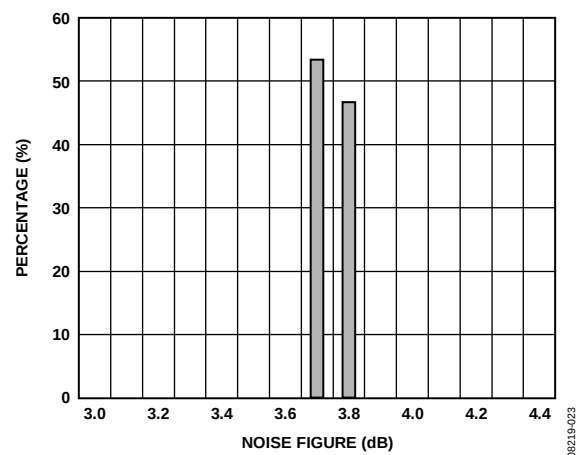


Figure 13. Noise Figure Distribution at 900 MHz

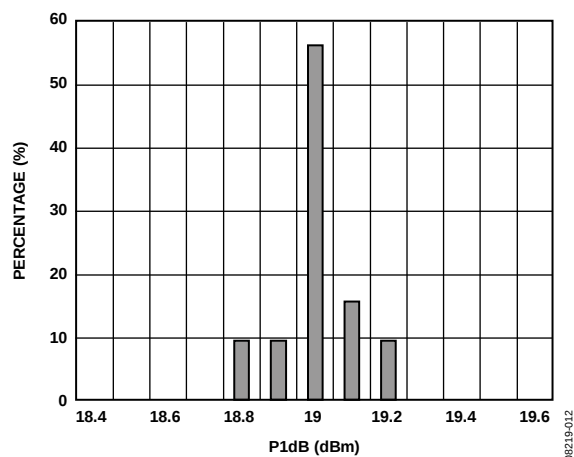


Figure 11. P1dB Distribution at 900 MHz

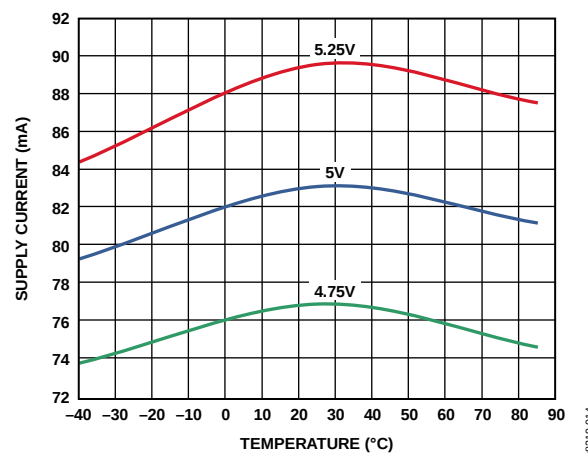


Figure 14. Supply Current vs. Temperature

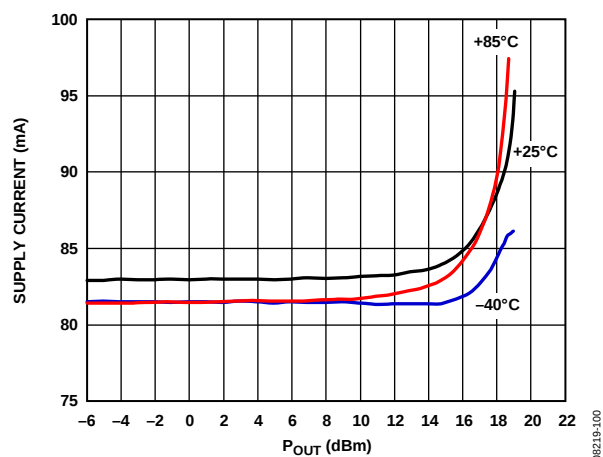


Figure 15. Supply Current vs. P_{OUT} and Temperature $V_{CC} = 5V$

BASIC CONNECTIONS

The basic connections for operating the [ADL5601](#) are shown in Figure 16. Recommended components are listed in Table 5. The input and output should be ac-coupled with appropriately sized capacitors (the device characterization was performed with 0.1 μF capacitors). A 5 V dc bias is supplied to the amplifier through the bias inductor connected to RFOUT (Pin 3). The bias voltage should be decoupled using a 1 μF capacitor, a 1.2 nF capacitor, and a 68 pF capacitor.

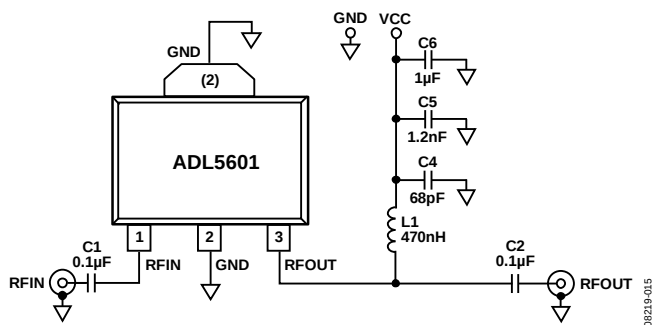


Figure 16. Basic Connections

SOLDERING INFORMATION AND RECOMMENDED PCB LAND PATTERN

Figure 17 shows the recommended land pattern for the [ADL5601](#). To minimize thermal impedance, the exposed paddle on the package underside, along with Pin 2, should be soldered to a ground plane. If multiple ground layers exist, they should be stitched together using vias. For more information on land pattern design and layout, refer to the [AN-772 Application Note, A Design and Manufacturing Guide for the Lead Frame Chip Scale Package \(LFCSP\)](#).

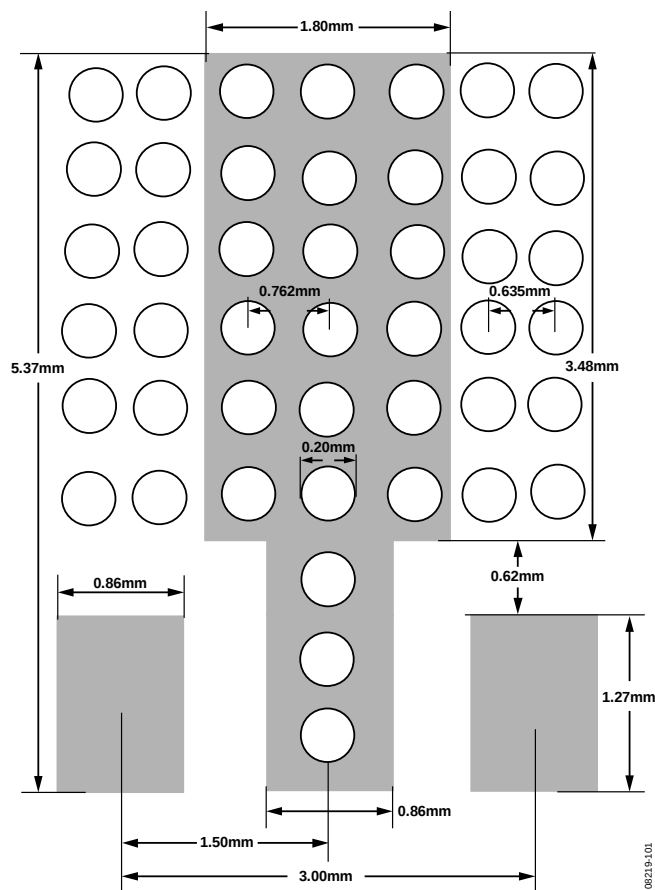


Figure 17. Recommended Land Pattern

Table 5. Recommended Components for Basic Connections

Frequency	C1	C2	L1	C4	C5	C6
50 MHz to 4000 MHz	0.1 μF	0.1 μF	470 nH (Coilcraft 0603LS-NX or equivalent)	68 pF	1.2 nF	1 μF

W-CDMA ACPR PERFORMANCE

Figure 18 shows a plot of the adjacent channel power ratio (ACPR) vs. P_{OUT} for the ADL5601. The signal type used is a single wideband code division multiple access (W-CDMA) carrier (Test Model 1, 64) at 2140 MHz. This signal is generated by a very low ACPR source. ACPR is measured at the output by a high dynamic range spectrum analyzer that incorporates an instrument noise-correction function.

The ADL5601 achieves an ACPR of -69 dBc at -5 dBm output, at which point device noise, rather than distortion, begins to dominate the power in the adjacent channels. At an output power of +5 dBm, ACPR is still very low at -56 dBc, making the device particularly suitable for power amplifier (PA) driver applications.

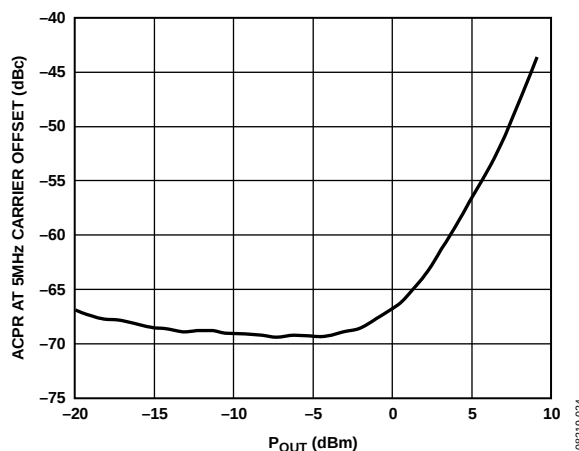


Figure 18. ACPR vs. P_{OUT} , Single W-CDMA Carrier (Test Model 1, 64) at 2140 MHz

EVALUATION BOARD

Figure 19 shows the evaluation board layout, and Figure 20 shows the schematic for the ADL5601 evaluation board. The board is powered by a single 5 V supply.

The components used on the board are listed in Table 6. Power can be applied to the board through clip-on leads (VCC and GND).

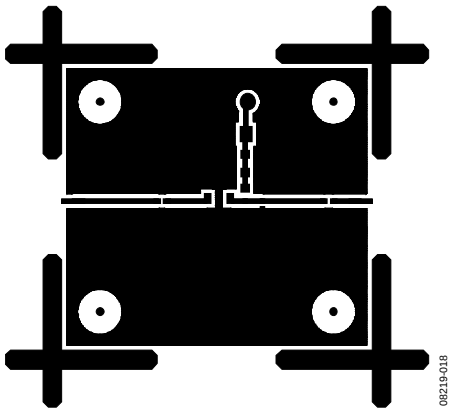


Figure 19. Evaluation Board Layout (Top)

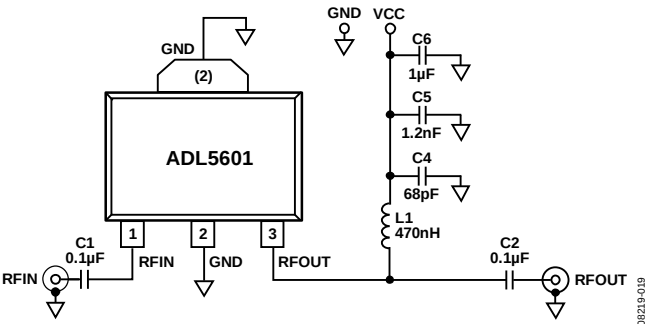
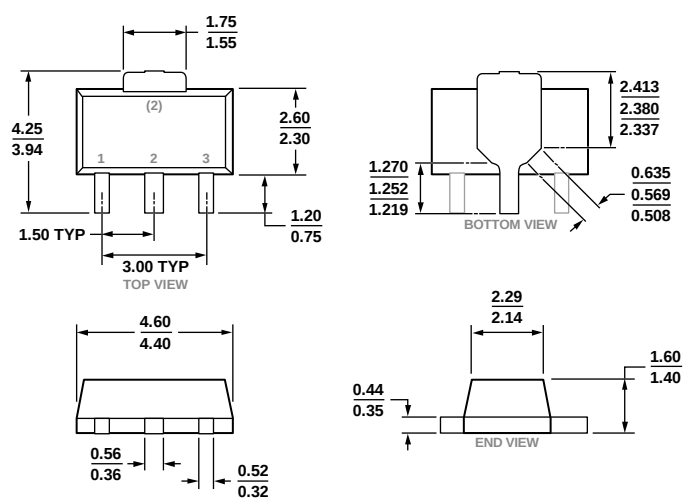


Figure 20. Evaluation Board Schematic

Table 6. Evaluation Board Configuration Options

Component	Description	Default Value
C1, C2	AC coupling capacitors	0.1 μF, 0402
L1	DC bias inductor	470 nH, 0603 (Coilcraft 0603LS-NX or equivalent)
VCC and GND	Clip-on terminals for power supply	
C4	Power supply decoupling capacitor	68 pF, 0603
C5	Power supply decoupling capacitor	1.2 nF, 0603
C6	Power supply decoupling capacitor	1 μF, 1206

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS TO-243

Figure 21. 3-Lead Small Outline Transistor Package [SOT-89]
(RK-3)

Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
ADL5601ARKZ-R7	−40°C to +85°C	3-Lead SOT-89, 7" Tape and Reel	RK-3
ADL5601-EVALZ		Evaluation Board	

¹ Z = RoHS Compliant Part.

NOTES